

# GD54/74HC20, GD54/74HCT20

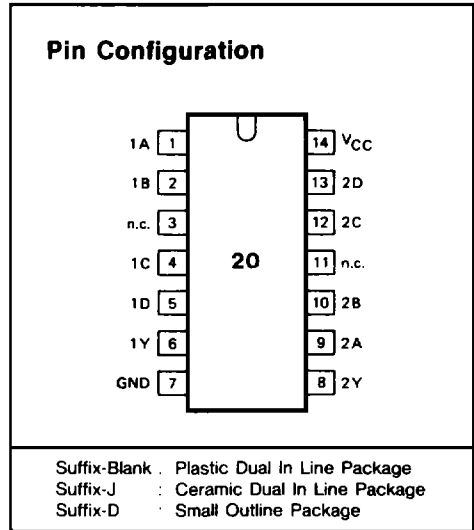
## DUAL 4-INPUT NAND GATES

### General Description

These devices are identical in pinout to the 54/74LS20. They contain two independent 4-input NAND gates. These devices are characterized for operation over wide temperature ranges to meet industry and military specifications.

### Features

- Low Power consumption characteristic of CMOS devices
- Output drive capability: 10 LS TTL Loads Min.
- Operating speed superior to LS TTL
- Wide operating voltage range: for HC 2 to 6 volts  
for HCT 4.5 to 5.5 volts
- Low input current: 1 $\mu$ A Max.
- Low quiescent current: 20 $\mu$ A Max. (74HC)
- High noise immunity characteristic of CMOS
- Diode protection on all inputs



### Function Table

INPUT				OUTPUT
nA	nB	nC	nD	nY
L	X	X	X	H
X	L	X	X	H
X	X	L	X	H
X	X	X	L	H
H	H	H	H	L

H=HiGH Voltage level  
L=LOW Voltage level  
X=don't care

### Logic Symbol and Diagram

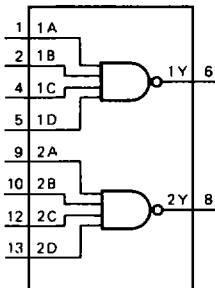


Fig. 1 Logic symbol

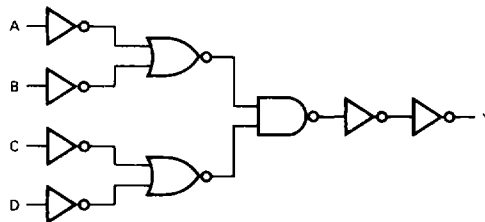


Fig. 2 Logic diagram (one gate)

**Absolute Maximum Ratings**

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
$V_{CC}$	DC Supply voltage		-0.5	+7	V
$I_{i}, I_{OK}$	DC input or output diode current	for $V_i < -0.5$ or $V_i > V_{CC} + 0.5V$		20	mA
$I_O$	DC output source or sink current	for $-0.5V < V_O < V_{CC} + 0.5V$		25	mA
$I_{CC}$	DC $V_{CC}$ or GND current			50	mA
$T_{stg}$	Storage temperature range		-65	150	°C
$P_D$	Power dissipation per package	above +70°C. derate linearly with 8mW/K		500	mW
$T_L$	Lead temperature	At distance 1/16 ± 1/32 in from case for 60 sec(CERAMIC) 10 sec(PLASTIC)		300 260	°C

**Recommended Operating Conditions**

CHARACTERISTIC	LIMITS		UNITS
	MIN	MAX	
Supply-Voltage Range $V_{CC}$ . GD54/74HC Types GD54/74HCT Types	2 4.5	6 5.5	V
DC Input or Output Voltage $V_i, V_O$	0	$V_{CC}$	V
Operating Temperature $T_A$ . GD74 Types GD54 Types	-40 -55	+85 +125	°C
Input Rise and Fall times $t_r, t_f$ GD54/74HC Types at 2V at 4.5V at 6V GD54/74HCT Types at 4.5V		1000 500 400 500	ns

DC Electrical Characteristics for HC

SYMBOL	PARAMETER	TEST CONDITION	V <sub>CC</sub> (V)	T <sub>A</sub> =25°C			GD74HC20		GD54HC20		UNIT	
				MIN.	TYP	MAX.	MIN.	MAX.	MIN.	MAX.		
V <sub>IH</sub>	HIGH level input Voltage		2.0	1.5			1.5		1.5		V	
			4.5	3.15			3.15		3.15			
			6.0	4.2			4.2		4.2			
V <sub>IL</sub>	LOW level input voltage		2.0			0.3		0.3		0.3	V	
			4.5			0.9		0.9		0.9		
			6.0			1.2		1.2		1.2		
V <sub>OH</sub>	HIGH level output voltage	V <sub>IN</sub> =V <sub>IH</sub>	I <sub>OH</sub> =-20μA	2.0	1.9	2.0		1.9		1.9	V	
				4.5	4.4	4.5		4.4		4.4		
				6.0	5.9	6.0		5.9		5.9		
		or V <sub>IL</sub>	I <sub>OH</sub> =-4mA	4.5	3.98	4.3		3.84		3.7		
				6.0	5.48	5.2		5.34		5.2		
				I <sub>OH</sub> =-5.2mA	4.5			0.1		0.1		
4.5		0.17	0.26			0.33		0.4				
6.0		0.15	0.26			0.33		0.4				
V <sub>OL</sub>	LOW level output voltage	V <sub>IN</sub> =V <sub>IH</sub>	I <sub>OL</sub> =20μA	2.0			0.1		0.1		V	
				4.5			0.1		0.1			0.1
				6.0			0.1		0.1			0.1
		or V <sub>IL</sub>	I <sub>OL</sub> =4mA	4.5		0.17	0.26		0.33			0.4
				6.0		0.15	0.26		0.33			0.4
				I <sub>OL</sub> =5.2mA	4.5							
4.5												
6.0												
I <sub>IN</sub>	Input leakage Current	V <sub>IN</sub> =V <sub>CC</sub> or GND	6.0			0.1		1.0		1.0	μA	
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> =V <sub>CC</sub> or GND I <sub>out</sub> =0μA	6.0			2		20		40	μA	

DC Electrical Characteristics for HCT

SYMBOL	PARAMETER	TEST CONDITION	V <sub>CC</sub> (V)	T <sub>A</sub> =25°C			GD74HCT20		GD54HCT20		UNIT	
				MIN	TYP	MAX	MIN	MAX	MIN	MAX		
V <sub>IH</sub>	HIGH level input Voltage		4.5								V	
			to	2.0			2.0		2.0			
			5.5									
V <sub>IL</sub>	LOW level input voltage		4.5								V	
			to			0.8		0.8		0.8		
			5.5									
V <sub>OH</sub>	HIGH level output voltage	V <sub>IN</sub> =V <sub>IH</sub>	I <sub>OH</sub> =-20μA	4.5	4.4	4.5		4.4		4.4	V	
				4.5	3.98	4.3		3.84		3.7		
				6.0								
		or V <sub>IL</sub>	I <sub>OH</sub> =-4mA	4.5			0.1		0.1			0.1
				4.5		0.17	0.26		0.33			0.4
				6.0								
V <sub>OL</sub>	LOW level output voltage	V <sub>IN</sub> =V <sub>IH</sub>	I <sub>OL</sub> =20μA	4.5			0.1		0.1		V	
				4.5			0.1		0.1			0.1
				6.0			0.1		0.1			0.1
		or V <sub>IL</sub>	I <sub>OL</sub> =4mA	4.5		0.17	0.26		0.33			0.4
				6.0								
				I <sub>OL</sub> =5.2mA	4.5							
4.5												
6.0												
I <sub>IN</sub>	Input leakage Current	V <sub>IN</sub> =V <sub>CC</sub> or GND	5.5			0.1		1.0		1.0	μA	
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> =V <sub>CC</sub> or GND I <sub>out</sub> =0μA	5.5			2		20		40	μA	

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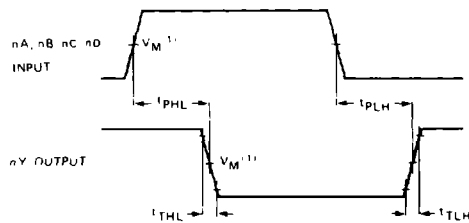
## AC Characteristics for HC: $t_r=t_f=6\text{ns}$ $C_L=50\text{pF}$

SYMBOL	PARAMETER	$V_{CC}$ (V)	$T_A=25^\circ\text{C}$			GD74HC20		GD54HC20		UNIT
			MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
$t_{PLH}$ / $t_{PHL}$	Propagation delay time nA, nB, nC, nD to nY	2.0		28	90		110		130	ns
		4.5		10	18		23		26	
		6.0		8	15		20		23	
$t_{TLH}$ / $t_{THL}$	Output transition time	2.0		25	70		85		100	ns
		4.5		8	15		18		22	
		6.0		7	13		16		19	

## AC Characteristics for HCT: $t_r=t_f=6\text{ns}$ $C_L=50\text{pF}$

SYMBOL	PARAMETER	$V_{CC}$ (V)	$T_A=25^\circ\text{C}$			GD74HCT20		GD54HCT20		UNIT
			MIN.	TYP.	MAX.	MIN.	MAX.	MIN.	MAX.	
$t_{PLH}$ / $t_{PHL}$	Propagation delay time nA, nB, nC, nD to nY	4.5		14	24		30		40	ns
$t_{TLH}$ / $t_{THL}$	Output transition time	4.5		8	15		18		22	ns

### AC Waveform



**Fig. 3** Waveforms showing the input (nA, nB, nC, nD) to output (nY) propagation delays and the output transition times.

#### Note to AC waveform

- (1) HC  $V_M=50\%$ .  $V_i=GND$  to  $V_{CC}$
- HCT  $V_M=1.3V$ .  $V_i=GND$  to  $3V$